General Purpose Transistors

PNP Silicon

Features

• These are Pb-Free Devices*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector - Emitter Voltage	V _{CEO}	-60	Vdc
Collector - Base Voltage	V _{CBO}	-60	Vdc
Emitter - Base Voltage	V _{EBO}	-5.0	Vdc
Collector Current - Continuous	I _C	-600	mAdc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	P _D	625 5.0	mW mW/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C	P _D	1.5 12	W mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	83.3	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

DEVICE MARKING

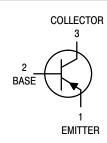
Device	Line 1	Line 2
MPS2907AG	MPS	2907A
MPS2907ARLG	MPS2	907A
MPS2907ARLRAG	MPS	2907
MPS2907ARLRPG	MPS	2907

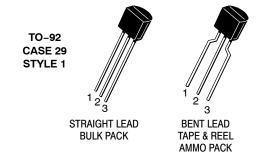
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



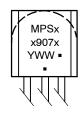
ON Semiconductor®

http://onsemi.com





MARKING DIAGRAM



Y = Year WW = Work Week ■ = Pb-Free Package

(Note: Microdot may be in either location)

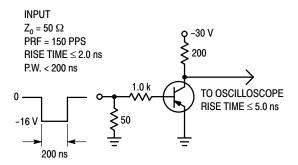
ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Ch	aracteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS			l .		
Collector - Emitter Breakdown Voltage	(Note 1) (I _C = -10 mAdc, I _B = 0)	V _{(BR)CEO}	-60	-	Vdc
Collector – Base Breakdown Voltage (I _C	; = -10 μAdc, I _E = 0)	V _{(BR)CBO}	-60	-	Vdc
Emitter – Base Breakdown Voltage (I _E =	-10 μAdc, I _C = 0)	V _{(BR)EBO}	-5.0	-	Vdc
Collector Cutoff Current (V _{CE} = -30 Vd	c, V _{EB(off)} = -0.5 Vdc)	I _{CEX}	-	-50	nAdc
Collector Cutoff Current $(V_{CB} = -50 \text{ Vdc}, I_E = 0)$ $(V_{CB} = -50 \text{ Vdc}, I_E = 0, T_A = 150^{\circ}\text{C})$		Ісво	- -	-0.01 -10	μAdc
Base Current (V _{CE} = -30 Vdc, V _{EB(off)}	= -0.5 Vdc)	I _B	-	-50	nAdc
ON CHARACTERISTICS				•	•
$\begin{array}{l} \text{DC Current Gain} \\ (I_{C} = -0.1 \text{ mAdc, V}_{CE} = -10 \text{ Vdc)} \\ (I_{C} = -1.0 \text{ mAdc, V}_{CE} = -10 \text{ Vdc)} \\ (I_{C} = -10 \text{ mAdc, V}_{CE} = -10 \text{ Vdc)} \\ (I_{C} = -150 \text{ mAdc, V}_{CE} = -10 \text{ Vdc)} \\ (I_{C} = -500 \text{ mAdc, V}_{CE} = -10 \text{ Vdc)} \end{array}$	Note 1) Note 1)	h _{FE}	75 100 100 100 50	- - - 300 -	-
	Note 1)	V _{CE(sat)}	- -	-0.4 -1.6	Vdc
Base – Emitter Saturation Voltage (Note (I _C = -150 mAdc, I _B = -15 mAdc) (I _C = -500 mAdc, I _B = -50 mAdc)	· 1)	V _{BE(sat)}	- -	-1.3 -2.6	Vdc
SMALL-SIGNAL CHARACTERISTICS	3		l .	I.	
Current – Gain – Bandwidth Product (No (I _C = –50 mAdc, V _{CE} = –20 Vdc, f =	, · · · · · · · · · · · · · · · · · · ·	f _T	200	_	MHz
Output Capacitance (V _{CB} = -10 Vdc, I _E	= 0, f = 1.0 MHz)	C _{obo}	-	8.0	pF
Input Capacitance (V _{EB} = -2.0 Vdc, I _C	= 0, f = 1.0 MHz)	C _{ibo}	-	30	pF
SWITCHING CHARACTERISTICS					
Turn-On Time	$(V_{CC} = -30 \text{ Vdc}, I_C = -150 \text{ mAdc},$	t _{on}	-	45	ns
Delay Time	$I_{B1} = -15$ mAdc) (Figures 1 and 5)	t _d	-	10	ns
Rise Time		t _r	-	40	ns
Turn-Off Time	$(V_{CC} = -6.0 \text{ Vdc}, I_{C} = -150 \text{ mAdc},$	t _{off}	-	100	ns
Storage Time	I _{B1} = I _{B2} = 15 mAdc) (Figure 2)	t _s	-	80	ns
Fall Time		t _f	-	30	ns

^{1.} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%. 2. f_T is defined as the frequency at which $|h_{fe}|$ extrapolates to unity.



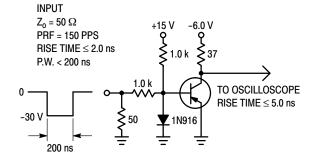


Figure 1. Delay and Rise Time Test Circuit

Figure 2. Storage and Fall Time Test Circuit

TYPICAL CHARACTERISTICS

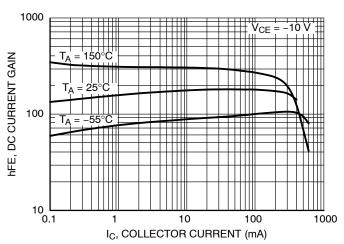


Figure 3. DC Current Gain

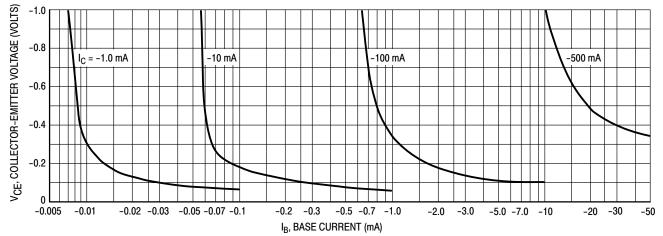


Figure 4. Collector Saturation Region

ORDERING INFORMATION

Device	Package	Shipping [†]
MPS2907AG	TO-92 (Pb-Free)	5000 Units / Bulk
MPS2907ARLG	TO-92 (Pb-Free)	0000 / Tana & Davi
MPS2907ARLRAG	TO-92 (Pb-Free)	2000 / Tape & Reel
MPS2907ARLRPG	TO-92 (Pb-Free)	2000 / Ammo Pack

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

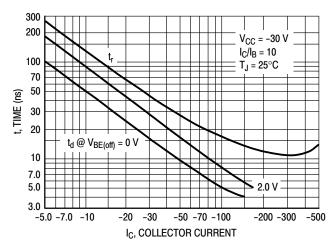


Figure 5. Turn-On Time

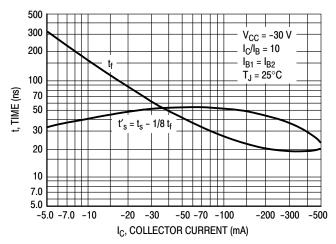


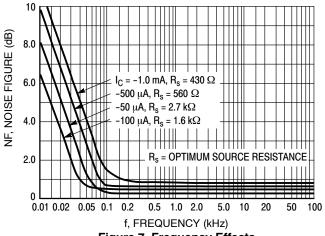
Figure 6. Turn-Off Time

TYPICAL SMALL-SIGNAL CHARACTERISTICS NOISE FIGURE

 V_{CE} = 10 Vdc, T_A = 25°C

10

50 100 200



1.0 k

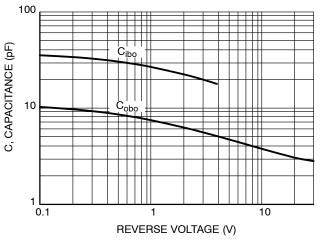
Figure 7. Frequency Effects

 $R_{\text{s}},$ SOURCE RESISTANCE (Ω) Figure 8. Source Resistance Effects

2.0 k

5.0 k

50 k



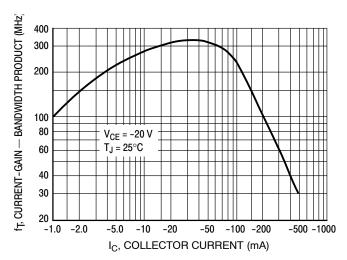
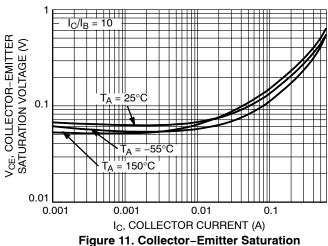
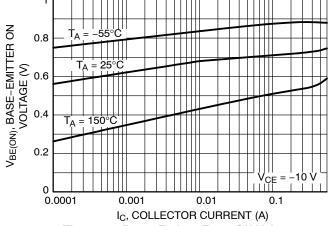


Figure 9. Capacitances

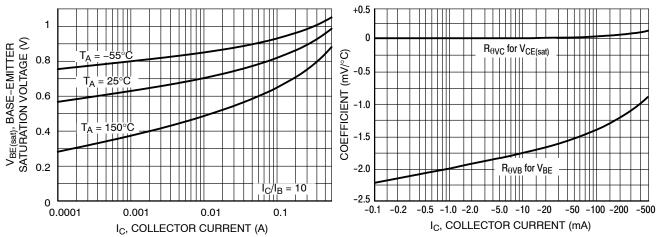
Figure 10. Current-Gain - Bandwidth Product





gure 11. Collector-Emitter Saturation Voltage vs. Collector Current

Figure 12. Base-Emitter Turn-ON Voltage vs. Collector Current



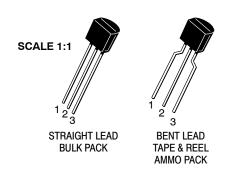
I_C, COLLECTOR CURRENT (A)

Figure 13. Base Emitter Saturation Voltage vs.

Collector Current

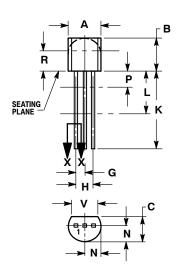
Figure 14. Temperature Coefficients





TO-92 (TO-226) CASE 29-11 **ISSUE AM**

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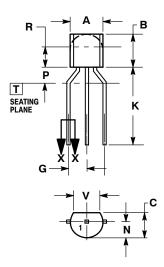


STRAIGHT LEAD **BULK PACK**



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
 4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
P		0.100		2.54
R	0.115		2.93	
٧	0.135		3.43	



BENT LEAD TAPE & REEL AMMO PACK



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
 4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	MILLIMETERS				
DIM	MIN	MAX			
Α	4.45	5.20			
В	4.32	5.33			
С	3.18	4.19			
D	0.40	0.54			
G	2.40	2.80			
J	0.39	0.50			
K	12.70				
N	2.04	2.66			
P	1.50	4.00			
R	2.93				
V	3.43				

STYLES ON PAGE 2

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TO-92 (TO-226) CASE 29-11

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STYLE 1: PIN 1. 2. 3.	EMITTER BASE COLLECTOR	STYLE 2: PIN 1. 2. 3.	BASE EMITTER COLLECTOR	STYLE 3: PIN 1. 2. 3.	ANODE ANODE CATHODE	STYLE 4: PIN 1. 2. 3.	CATHODE CATHODE ANODE	STYLE 5: PIN 1. 2. 3.	DRAIN
2.	GATE SOURCE & SUBSTRATE DRAIN	STYLE 7: PIN 1. 2. 3.	SOURCE DRAIN GATE	STYLE 8: PIN 1. 2. 3.	DRAIN GATE SOURCE & SUBSTRATE	PIN 1.	BASE 1		CATHODE
2.	ANODE CATHODE & ANODE CATHODE	STYLE 12: PIN 1. 2. 3.	MAIN TERMINAL 1 GATE MAIN TERMINAL 2	PIN 1.	ANODE 1	PIN 1.	EMITTER COLLECTOR BASE	PIN 1. 2.	
2.	ANODE GATE	PIN 1. 2.	COLLECTOR BASE	PIN 1. 2.	ANODE CATHODE	PIN 1. 2.	GATE	2.	NOT CONNECTED
2.	COLLECTOR	PIN 1. 2.	SOURCE GATE DRAIN	STYLE 23: PIN 1. 2. 3.	GATE SOURCE DRAIN	STYLE 24: PIN 1. 2. 3.	EMITTER COLLECTOR/ANODE CATHODE	STYLE 25: PIN 1. 2. 3.	MT 1 GATE
	V _{CC}	PIN 1. 2.	MT	STYLE 28: PIN 1. 2.	CATHODE ANODE GATE	STYLE 29: PIN 1. 2.		PIN 1. 2.	DRAIN
	GATE	PIN 1. 2.		STYLE 33: PIN 1. 2. 3.	RETURN	2.			

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PAGE 3 OF 3

ISSUE	REVISION	DATE
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